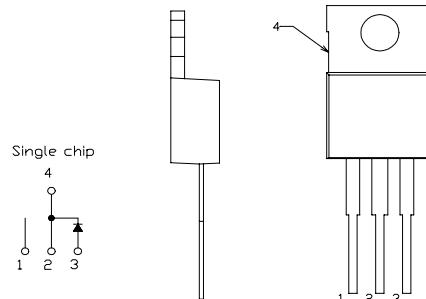


SBD Type : GSQ05A04B

OUTLINE DRAWING

FEATURES

- *Similar to TO-220AC Case
- *Low Forward Voltage Drop
- *Low Power Loss, High Efficiency
- *High Surge Capability
- * $T_j=150^\circ\text{C}$ operation



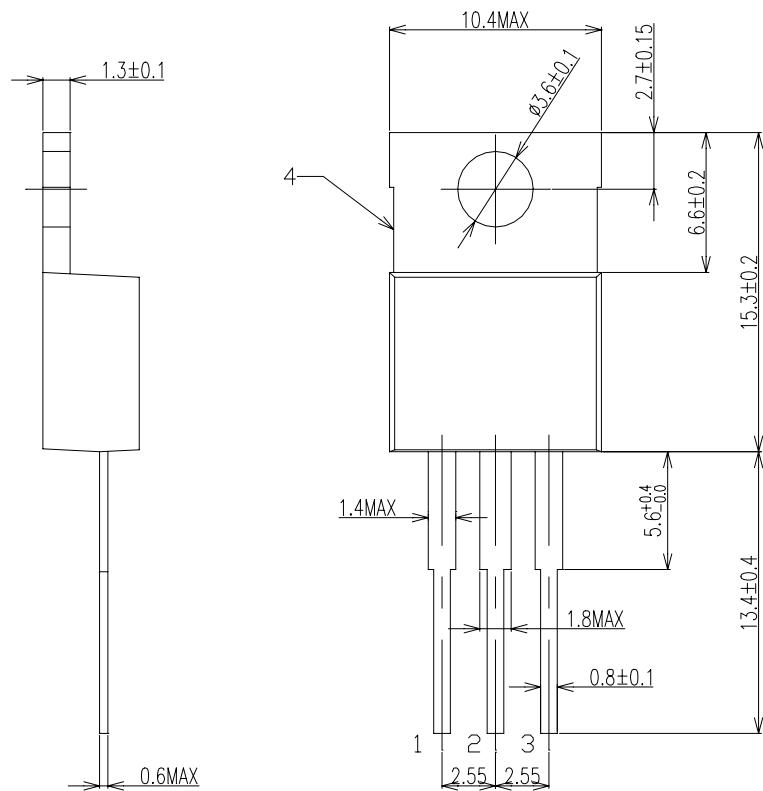
Maximum Ratings

Approx Net Weight: 1.9g

Rating	Symbol	GSQ05A04B				Unit					
Repetitive Peak Reverse Voltage	V_{RRM}	40				V					
Average Rectified Output Current	I_o	5	$T_c=122^\circ\text{C}$	50 Hz half Sine Wave Resistive Load		A					
RMS Forward Current	$I_{F(RMS)}$	7.85				A					
Surge Forward Current	I_{FSM}	120	50Hz Half Sine Wave ,1cycle Non-repetitive			A					
Operating JunctionTemperature Range	T_{jw}	-40 to +150				°C					
Storage Temperature Range	T_{stg}	-40 to +150				°C					
Mounting torque	F_{tor}	recommended torque = 0.5				N•m					

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j= 25^\circ\text{C}, V_{RM}= V_{RRM}$	-	-	5	mA
Peak Forward Voltage	V_{FM}	$T_j= 25^\circ\text{C}, I_{FM}= 5 \text{ A}$	-	-	0.55	V
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	5	°C/W

GSQ05A04B OUTLINE DRAWING (Dimention in mm)

Single chip
